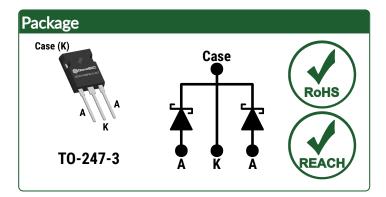
# GeneSic SEMICONDUCTOR

#### Silicon Carbide Schottky Diode

VRRM = 1200 V IF (Tc = 135°C) = 38 A \* QC = 106 nC \*

#### **Features**

- Low V<sub>F</sub> for High Temperature Operation
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Q<sub>C</sub>/I<sub>F</sub>
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V<sub>F</sub>
- High dV/dt Ruggedness



#### **Advantages**

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Enables Extremely Fast Switching

## **Applications**

- Power Factor Correction (PFC)
- Solar Inverters
- Battery Chargers
- High Frequency Converters
- Switched Mode Power Supply (SMPS)
- AC/DC Power Supplies
- Anti-Parallel / Free-Wheeling Diode
- LED and HID Lighting

Absolute Maximum Ratings (At Tc = 25°C Unless Otherwise Stated)								
Parameter	Symbol	Conditions Values		Unit	Note			
Repetitive Peak Reverse Voltage (Per Leg)	$V_{RRM}$		1200	٧				
Continuous Forward Current (Per Leg / Per Device)		$T_C = 100^{\circ}C, D = 1$	28 / 56					
	l <sub>F</sub>	$T_C = 135^{\circ}C$ , $D = 1$	19 / 38	Α	Fig. 4			
		$T_C = 162^{\circ}C$ , D = 1	10 / 20					
Non-Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	leou	$T_C$ = 25°C, $t_P$ = 10 ms	100	Α				
	I <sub>F,SM</sub>	$T_C = 150^{\circ}C$ , $t_P = 10 \text{ ms}$	80					
Repetitive Peak Forward Surge Current, Half Sine Wave	lenu	$T_C = 25^{\circ}C$ , $t_P = 10 \text{ ms}$ 60		Α				
(Per Leg)	I <sub>F,RM</sub>	$T_C = 150^{\circ}C$ , $t_P = 10 \text{ ms}$	42	Α				
Non-Repetitive Peak Forward Surge Current (Per Leg)	I <sub>F,MAX</sub>	$T_C = 25^{\circ}C$ , $t_P = 10 \mu s$	500	Α				
i <sup>2</sup> t Value (Per Leg)	∫i²dt	$T_C = 25^{\circ}C$ , $t_P = 10 \text{ ms}$	50	$A^2s$				
Non-Repetitive Avalanche Energy (Per Leg)	E <sub>AS</sub>	$L = 3.6 \text{ mH}, I_{AS} = 10 \text{ A}$	180	mJ				
Diode Ruggedness (Per Leg)	dV/dt	$V_R = 0 \sim 960 \text{ V}$	200	V/ns				
Power Dissipation (Per Leg / Per Device)	P <sub>TOT</sub>	T <sub>C</sub> = 25°C	215 / 430	W	Fig. 3			
Operating and Storage Temperature	$T_j$ , $T_{stg}$		-55 to 175	°C				

<sup>\*</sup> Per Device





Electrical Characteristics (Per Leg)								
Symbol	Conditions		Values			Unit	Note	
Symbol			Min.	Тур.	Max.	Ullit	Note	
V-	I <sub>F</sub> = 10 A, T <sub>j</sub> = 25°C			1.5	1.8	٧	Fig. 1	
VF	I <sub>F</sub> = 10 A, T <sub>j</sub> = 175°C			1.9				
l <sub>a</sub>	V <sub>R</sub> = 1200 V, T <sub>j</sub> = 25°C			1	5	μΑ	Fig. 2	
IR	$V_R = 1200 \text{ V, T}_j = 175^{\circ}\text{C}$			11				
0.		V <sub>R</sub> = 400 V		37		nC	Fig. 7	
QС	_ l <sub>F</sub> ≤ l <sub>F,MAX</sub> _ dl <sub>F</sub> /dt = 200 A/μs	$V_R = 800 V$		53				
+-		V <sub>R</sub> = 400 V		- 10		ns		
ιs		$V_R = 800 V$		< 10				
C	V <sub>R</sub> = 1 V, f =	= 1MHz		609		nE	Fig. 6	
	$V_R = 800 \text{ V, f} = 1 \text{MHz}$			36		pr	Fig. 6	
	(Per Leg)  Symbol  V <sub>F</sub> I <sub>R</sub> Q <sub>C</sub> t <sub>S</sub> C	$ \begin{array}{c c} \textbf{Symbol} & \textbf{Conditi} \\ V_F & I_F = 10 \text{ A, T}_j \\ I_F = 10 \text{ A, T}_j \\ V_R = 1200 \text{ V, T} \\ V_R = 1200 \text{ V, T} \\ \hline \\ Q_C & I_F \leq I_{F,MAX} \\ dI_F/dt = 200 \text{ A/}\mu\text{s} \\ \hline \\ C & V_R = 1 \text{ V, f = } \\ \end{array} $	$\begin{array}{c} \text{Symbol} & \text{Conditions} \\ \\ V_F & I_F = 10 \text{ A, } T_j = 25^{\circ}\text{C} \\ I_F = 10 \text{ A, } T_j = 175^{\circ}\text{C} \\ \\ I_R & V_R = 1200 \text{ V, } T_j = 25^{\circ}\text{C} \\ \\ V_R = 1200 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 1200 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 400 \text{ V} \\ \\ V_R = 800 \text{ V} \\ \\ V_R = 1 \text{ V, } f = 1 \text{ MHz} \\ \\ \end{array}$	$\begin{tabular}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

Thermal/Package Characteristics							
Parameter	Symbol	Conditions	Values			Unit	Note
		Contaitions	Min.	Typ.	Max.	Ullit	Note
Thermal Resistance, Junction - Case (Per Leg)	$R_{\text{thJC}}$			0.7		°C/W	Fig. 9
Weight	W <sub>T</sub>			6.1		g	
Mounting Torque	T <sub>M</sub>	Screws to Heatsink			1.1	Nm	





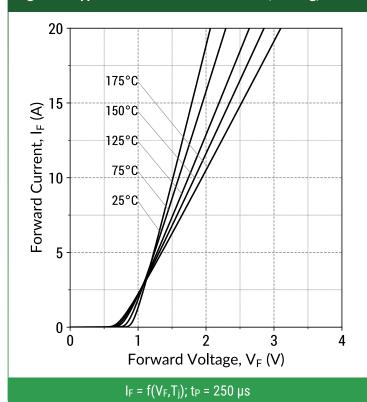
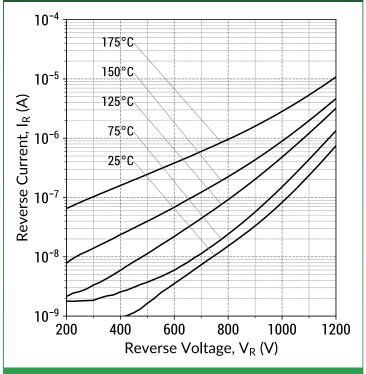


Figure 2: Typical Reverse Characteristics (Per Leg)



 $I_R = f(V_R, T_j)$ 

Figure 3: Power Derating Curves (Per Leg)

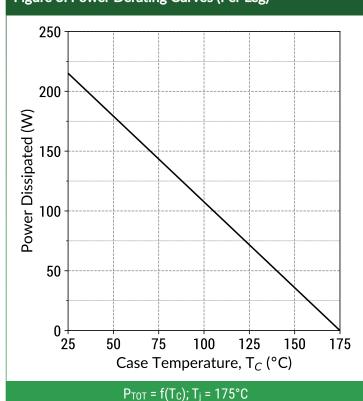
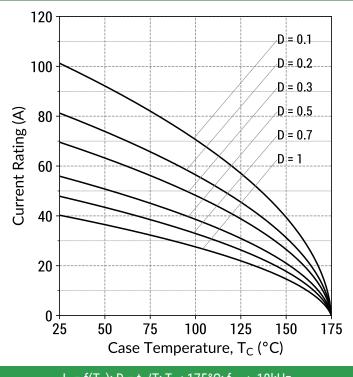


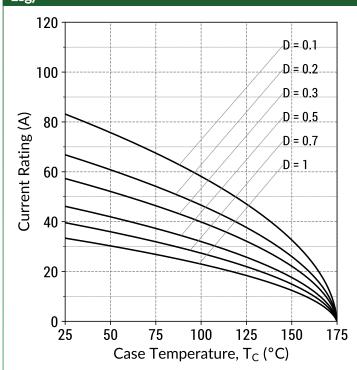
Figure 4: Current Derating Curves (Typical V<sub>F</sub>) (Per Leg)



 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$ 

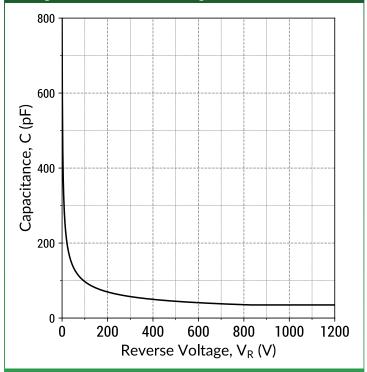


Figure 5: Current Derating Curves (Maximum V<sub>F</sub>) (Per



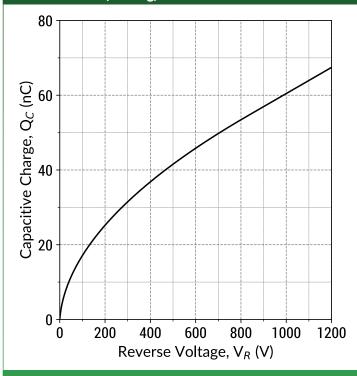
 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$ 

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



 $C = f(V_R)$ ; f = 1MHz

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)



 $Q_C = f(V_R); f = 1MHz$ 

Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)

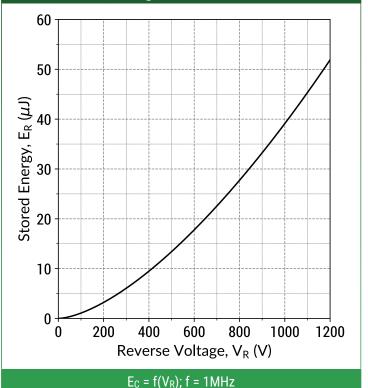
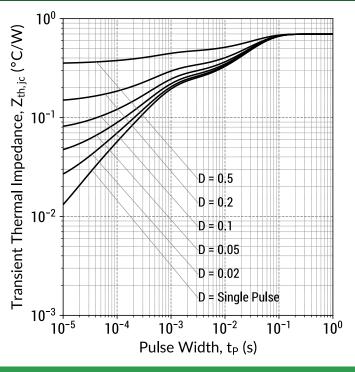


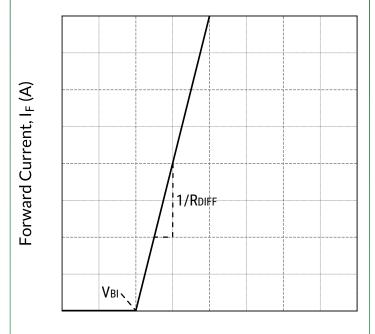


Figure 9: Transient Thermal Impedance (Per Leg)



 $Z_{th,jc} = f(t_P,D); D = t_P/T$ 

Figure 10: Forward Curve Model (Per Leg)



Forward Voltage,  $V_F$  (V)

 $I_F = f(V_F, T_j)$ 

#### Forward Curve Model Equation:

 $I_F = (V_F - V_{BI})/R_{DIFF}(A)$ 

#### Built-In Voltage (V<sub>BI</sub>):

$$V_{BI}(T_j) = m \times T_j + n (V)$$
  
 $m = -0.00123 (V/^{\circ}C)$   
 $n = 0.995 (V)$ 

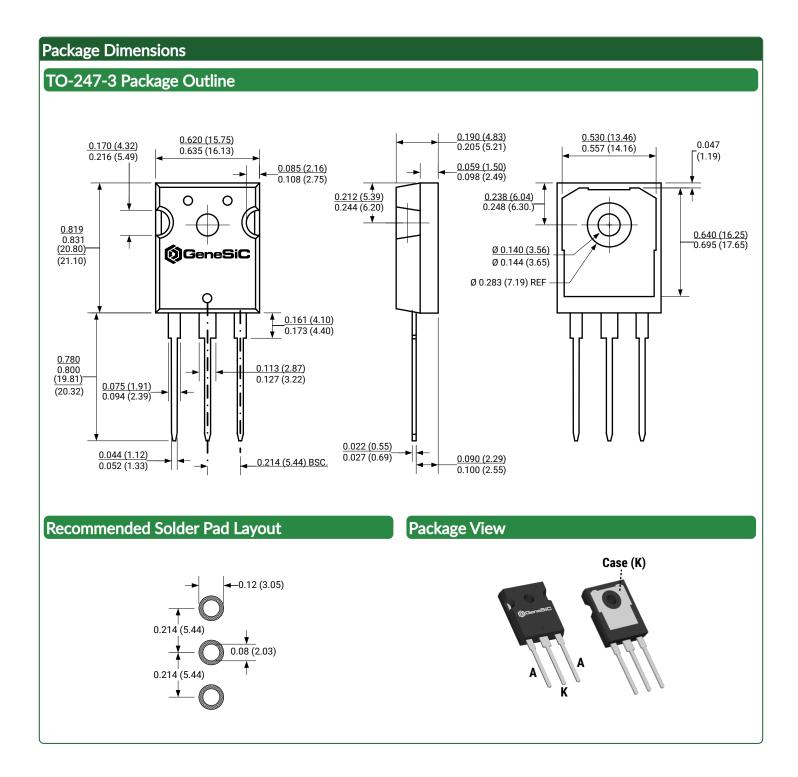
#### Differential Resistance (RDIFF):

$$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c (\Omega)$$
  
 $a = 1.19e-06 (\Omega/^{\circ}C^2)$   
 $b = 0.000169 (\Omega/^{\circ}C)$   
 $c = 0.0502 (\Omega)$ 

#### **Forward Power Loss Equation:**

 $P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$ 





#### NOTE

- 1. CONTROLLED DEIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
- 2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.





### **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

#### **REACH Compliance**

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

GeneSiC disclaims all and any warranty and liability arising out of use or application of any product. No license, express or implied to any intellectual property rights is granted by this document.

#### **Related Links**

SPICE Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X10MPS12-247/GC2X10MPS12-247\_SPICE.zip
 PLECS Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X10MPS12-247/GC2X10MPS12-247\_PLECS.zip
 CAD Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X10MPS12-247/GC2X10MPS12-247\_3D.zip

Evaluation Boards: https://www.genesicsemi.com/technical-support

Reliability: https://www.genesicsemi.com/reliability
 Compliance: https://www.genesicsemi.com/compliance
 Quality Manual: https://www.genesicsemi.com/quality

www.genesicsemi.com/sic-schottky-mps/



